

PATENT ASSIGNMENT

Electronic Version v1.1

Stylesheet Version v1.1

SUBMISSION TYPE:	NEW ASSIGNMENT												
NATURE OF CONVEYANCE:	ASSIGNMENT												
CONVEYING PARTY DATA													
<table border="1"> <thead> <tr> <th>Name</th> <th>Execution Date</th> </tr> </thead> <tbody> <tr> <td>Chao-Wei Tseng</td> <td>03/06/2012</td> </tr> <tr> <td>Kun-Ming Huang</td> <td>02/24/2012</td> </tr> <tr> <td>Cheng-Chi Chuang</td> <td>02/24/2012</td> </tr> <tr> <td>Fu-Hsiung Yang</td> <td>02/24/2012</td> </tr> </tbody> </table>		Name	Execution Date	Chao-Wei Tseng	03/06/2012	Kun-Ming Huang	02/24/2012	Cheng-Chi Chuang	02/24/2012	Fu-Hsiung Yang	02/24/2012		
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<table border="1"> <tr> <td>Name:</td> <td>Taiwan Semiconductor Manufacturing Company, Ltd.</td> </tr> <tr> <td>Street Address:</td> <td>No. 8, Li-Hsin Rd. 6</td> </tr> <tr> <td>Internal Address:</td> <td>Science-Based Industrial Park</td> </tr> <tr> <td>City:</td> <td>Hsin-Chu</td> </tr> <tr> <td>State/Country:</td> <td>TAIWAN</td> </tr> <tr> <td>Postal Code:</td> <td>300-77 R.O.C.</td> </tr> </table>		Name:	Taiwan Semiconductor Manufacturing Company, Ltd.	Street Address:	No. 8, Li-Hsin Rd. 6	Internal Address:	Science-Based Industrial Park	City:	Hsin-Chu	State/Country:	TAIWAN	Postal Code:	300-77 R.O.C.
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PROPERTY NUMBERS Total: 1													
<table border="1"> <thead> <tr> <th>Property Type</th> <th>Number</th> </tr> </thead> <tbody> <tr> <td>Application Number:</td> <td>13410135</td> </tr> </tbody> </table>		Property Type	Number	Application Number:	13410135								
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CORRESPONDENCE DATA													
<p>Fax Number: (972)732-9218</p> <p>Phone: 972-732-1001</p> <p>Email: docketing@slater-matsil.com</p> <p><i>Correspondence will be sent to the e-mail address first; if that is unsuccessful, it will be sent via US Mail.</i></p> <p>Correspondent Name: Slater & Matsil, L.L.P.</p> <p>Address Line 1: 17950 Preston Road</p> <p>Address Line 2: Suite 1000</p> <p>Address Line 4: Dallas, TEXAS 75252</p>													
ATTORNEY DOCKET NUMBER:	TSM11-1184												
NAME OF SUBMITTER:	Lauran M. White												
<p>Total Attachments: 2</p> <p>source=TSM11-1184_assignment#page1.tif</p> <p>source=TSM11-1184_assignment#page2.tif</p>													

CH \$40.00 13410135

PATENT

ASSIGNMENT

WHEREAS, I, the undersigned inventor (or one of the undersigned joint inventors), of residence as listed, having invented certain new and useful improvements as below entitled, for which application for United States Letters Patent is made, the said application having been executed on the date set forth below; and

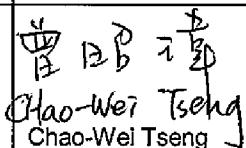
WHEREAS, Taiwan Semiconductor Manufacturing Company, Ltd. (TSMC), a corporation organized and existing under the laws of Taiwan, the Republic of China, with its principal office at No. 8, Li-Hsin Rd. 6, Science-Based Industrial Park, Hsin-Chu, Taiwan 300-77, R.O.C., is desirous of acquiring my entire right, title and interest in and to the said invention, and to the said application and any Letters Patent that may issue thereon in the United States and all other countries throughout the world;

NOW, THEREFORE, for good and valuable consideration, the receipt of which is hereby acknowledged, I hereby sell and assign to the said TSMC, its successors and assigns, my entire right, title and interest in and to the said invention and in to the said application and all patents which may be granted therefor, and all divisions, reissues, substitutions, continuations, and extensions thereof; and I hereby authorize and request the Commissioner for Patents to issue all patents for said invention, or patent resulting therefrom, insofar as my interest is concerned, to the said TSMC, as assignee of my entire right, title and interest. I declare that I have not executed and will not execute any agreement in conflict herewith.

I also hereby sell and assign to TSMC, its successors and assigns, my foreign rights to the invention disclosed in said application, in all countries of the world, including, but not limited to, the right to file applications and obtain patents under the terms of the International Convention for the Protection of Industrial Property, and of the European Patent Convention, and further agree to execute any and all patent applications, assignments, affidavits, and any other papers in connection therewith necessary to perfect such patent rights.

I hereby further agree that I will communicate to said TSMC, or to its successors, assigns, and legal representatives, any facts known to me respecting said invention or the file history thereof, and at the expense of said assignee company, testify in any legal proceedings, sign all lawful papers, execute all divisional, continuation, reissue and substitute applications, make all lawful oaths, and generally do everything possible to aid said TSMC, its successors, assigns and nominees to obtain and enforce proper patent protection for said invention in all countries.

IN WITNESS WHEREOF, I hereunto set my hand and seal this day and year;

TITLE OF INVENTION	Apparatus and Method for High Voltage MOS Transistor			
SIGNATURE OF INVENTOR AND NAME	 Chao-Wei Tseng	Kun-Ming Huang	Cheng-Chi Chuang	Fu-Hsiung Yang
DATE	3/6 '11			
RESIDENCE (City, County, State)	Jhonghe City, Taiwan	Taipei City, Taiwan	Zhonghe City, Taiwan	Zhongli City, Taiwan

ATTORNEY DOCKET NO.
TSM11-1184

ASSIGNMENT

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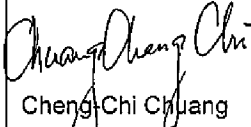
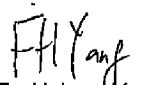
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SIGNATURE OF INVENTOR AND NAME	Chao-Wei Tseng	 Kun-Ming Huang	 Cheng-Chi Chuang	 Fu-Hsiung Yang
DATE		2/24/2012	Feb. 24	2/24/2012
RESIDENCE (City, County, State)	Jhonghe City, Taiwan	Taipei City, Taiwan	Zhonghe City, Taiwan	Zhongli City, Taiwan